

**Amendments to the Specification:**

Please amend the specification by inserting the paragraph below, after the title on page 1.

**Cross-Reference to Related Application**

[0001.1] This application claims priority based on International Patent Application No. PCT/FR02003/050044, entitled "Method for the Production of a Composite SICOI-Type Substrate Comprising an Epitaxy Stage" by Lea Di Cioccio, Francois Templier, Thierry Billon and Fabrice Letertre, which claims priority of French Application No. 02/10884, filed on September 3, 2002, and which was not published in English.